NSN 5961-00-498-5643

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-498-5643 **Inclosure Material:** Glass **Overall Length:** 0.205 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.107 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 5.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 3.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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